NSN 5961-00-412-2373
Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-412-2373
nclosure Material:
Metal
Overall Length:
1.635 inches
Mounting Facility Quantity:
1
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
1.690 inches
Thread Size:
0.750 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
300.0 nonrepetitive peak reverse voltage, peak total value, gate terminal open-circuited
Current Rating Per Characteristic:
40.00 milliamperes gate trigger current, instantaneous
Power Rating Per Characteristic:
3.0 watts average gate power-forward
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Thread Series Designator:
Jnf
Terminal Type And Quantity:
3 insulated wire lead w/terminal lug
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Filg:
A110a0